

# **General Description**

SSF102 is a small 8pin DFN packaged customized ASIC with configurable parameters. It supports frequency division and in-phase output function.

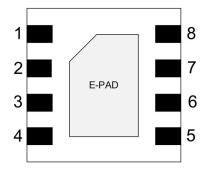
#### **Features**

- Power supply input: 2.3V~5.5V
- OUT1, 1x Push Pull Digital Output, 24.576Mhz output
- OUT2, 1x Push Pull Digital Output, 6.144Mhz output
- GND Power Ground
- OUT3, 1x Push Pull Digital Output 96Khz output
- NC Not Connected, Internal pull-down 1M
- IN Digital input with Schmitt, Internal pull-down 1M, 24.576Mhz input
- DFN 8 Package

## **Applications**

- Ultra low power consumption
- Pb Free and RoHS Compliant and Halogen Free

### **Pin Configurations**

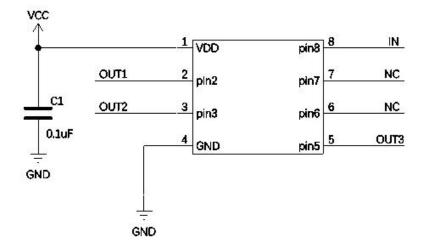


2.0mm x 2.0mm 8 Pin DFN Top View

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## **Block Diagram**



#### Note:

- 1. Voltage on any pin must be with in GND to VDD.
- 2. ESD protect is must be considered on all Pins which connected to external interface.

#### Pin name

| Pin | Pin  | ТҮРЕ                        | Function                                |
|-----|------|-----------------------------|---|
| 1   | VDD  | Power                       | Power supply input, 2.3V~5.5V           |
| 2   | OUT1 | 1x Push Pull Digital Output | 24.576Mhz output.                       |
| 3   | OUT2 | 1x Push Pull Digital Output | 6.144Mhz output.                        |
| 4   | GND  | Power                       | Ground                                  |
| 5   | OUT3 | 1x Push Pull Digital Output | 96Khz output.                           |
| 6   | NC   | Not Connected               | Internal pull-down 1M                   |
| 7   | NC   | Not Connected               | Internal pull-down 1M                   |
| 8   | IN   | Digital input with Schmitt  | Internal pull-down 1M, 24.576Mhz input. |

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# **Absolute Maximum Ratings**

| Parameter                        | Min. | Max. | Unit |
|----------------------------------|------|------|------|
| Supply Voltage on VDD to GND     | -0.3 | 7    | V    |
| Maximum Voltage Input to Pins    | -0.3 | 7    | V    |
| VDD to GND Maximum DC Current    |      | 90   | mA   |
| Input Leakage Current            |      | 1000 | nA   |
| Storage Temperature Range        | -65  | 150  | °C   |
| Junction Temperature             |      | 150  | °C   |
| ESD Protection (HBM)             | 2000 |      | V    |
| ESD Protection (CDM)             | 500  |      | V    |
| Moisture Sensitivity Level (MSL) |      | 1    |      |

### **Customize Electrical Characteristics**

VDD = $3.3V\pm10\%$ , Temp= $25^{\circ}$ C

| Symbol | Parameter         | Condition/Note                     | Min. | Тур. | Max. | Unit |
|--------|-------------------|------------------------------------|------|------|------|------|
| lα     | Quiescent Current | Static inputs and floating outputs |      | 0.1  |      | μΑ   |

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### **Electrical Characteristics**

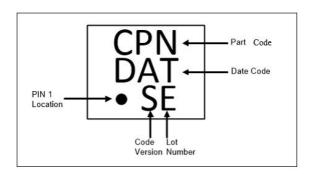
VDD =3.3V±10%, Temp: -40~85°C

| Symbol                | Parameter                                    | Condition/Note                                | Min. | Тур.   | Max.  | Uni        |
|-----------------------|--|---|------|--|-------|------------|
| V <sub>DD</sub>       | Supply Voltage                               |   | 1.71 | 3.3  | 5.5   | V          |
| T <sub>A</sub>        | Operating Temperature                        |   | -40  | 25   | 85    | °C         |
| C <sub>VDD</sub>      | Capacitor Value at VDD                       |   |      | 0.1  |       | μF         |
| I <sub>IH</sub>       | HIGH-Level Input Current                     | Logic Input PINs; V <sub>IN</sub> = VDD       | -1.0 |  | 1.0   | μΑ         |
| I <sub>IL</sub>       | LOW-Level Input Current                      | Logic Input PINs; V <sub>IN</sub> = 0V        | -1.0 |  | 1.0   | μΔ         |
| POR                   |  |   |      |  |       |            |
| $PON_{THR}$           | Power On Threshold                           | VDD Level Required to Start Up                | 1.67 | 1.80   | 1.92  | V          |
| POFF <sub>THR</sub>   | Power Off Threshold                          | VDD Level Required to Switch Off              | 0.95 | 1.25   | 1.54  | V          |
| $T_{SU}$              | Startup Time                                 | From VDD rising past PON <sub>THR</sub>       |      | 1.2  | 1.6   | m:         |
| I <sub>stand_by</sub> |  | T=+25℃  |      | 97   |       | n/         |
| O PIN                 |  |   |      |  |       |            |
|                       | HIGH-Level Input Voltage                     | Logic Input                                   | 1.90 |  |       | ٧          |
| $V_{IH}$              |  | Logic Input with Schmitt Trigger              | 2.11 |  |       | ٧          |
|                       |  | Low-Level Logic Input                         | 0.92 |  |       | V          |
|                       | LOW-Level Input Voltage                      | Logic Input                                   |      |  | 1.30  | ٧          |
| $V_{IL}$              |  | Logic Input with Schmitt Trigger              |      |  | 1.16  | V          |
|                       |  | Low-Level Logic Input                         |      |  | 0.77  | V          |
| $V_{HYS}$             | SchmittTrigger Hysteresis<br>Voltage         | Logic Input with Schmitt Trigger              |      | 0.45   |       | V          |
| I <sub>LKG</sub>      | Input leakage (Absolute Value)               |   |      | 1  | 1000  | n <i>A</i> |
| M                     | HIGH-Level Outpu Voltage                     | Push-Pull, I <sub>OH</sub> = 3 mA, 1X Drive   | 2.60 |  |       | ٧          |
| V <sub>OH</sub>       |  | Push-Pull, I <sub>OH</sub> = 3 mA, 2X Drive   | 2.80 |  |       | ٧          |
|                       |  | Push-Pull, I <sub>OL</sub> = 3 mA, 1X Drive   |      | 3.3 5.5  25 85  0.1  1.0  1.0  1.80 1.92  1.25 1.54  1.2 1.6  97     1.30   1.16   0.45   1 1000    1 1000 | 0.25  | V          |
|                       | LOW-Level Output Voltage                     | Push-Pull, I <sub>OL</sub> = 3 mA, 2X Drive   |      |  | 0.22  | V          |
| V <sub>OL</sub>       |  | Open Drain, I <sub>OL</sub> = 3 mA, 1X Drive  |      |  | 0.12  | V          |
|                       |  | Open Drain, I <sub>OL</sub> = 3 mA, 2X Drive  |      |  | 0.089 | ٧          |
|                       | HIGH-Level Output Pulse Current (see Note)   | Push-Pull, V <sub>OH</sub> = 2.4 V , 1X Drive | 5    |  |       | m          |
| I <sub>OH</sub>       |  | Push-Pull, V <sub>OH</sub> = 2.4 V, 2X Drive  | 10   |  |       | m          |
| I <sub>OL</sub>       | LOW-Level Output Pulse Current<br>(see Note) | Push-Pull, V <sub>OL</sub> = 0.4 V, 1X Drive  | 5    |  |       | m          |
|                       |  | Push-Pull, V <sub>OL</sub> = 0.4 V, 2X Drive  | 10   |  |       | m          |
|                       |  | Open Drain, V <sub>OL</sub> = 0.4 V, 1X Drive | 15   |  |       | m          |
|                       |  | Open Drain, V <sub>OL</sub> = 0.4 V, 2X Drive | 30   |  |       | m          |

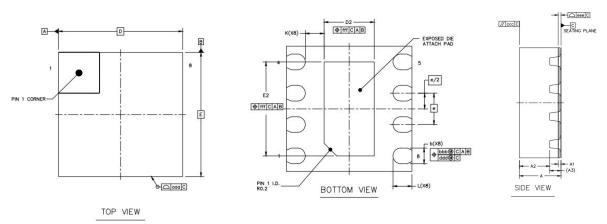
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# **Package Top Marking**



# **Package Drawing and Dimensions**



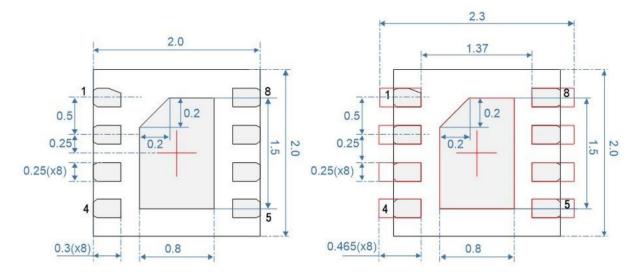
|                        |           | SYMBOL | MIN       | NOM  | MAX  |  |
|------------------------|-----------|--------|-----------|------|------|--|
| TOTAL THICKNESS        |           | A      | 0.7       | 0.75 | 0.8  |  |
| STAND OFF              |           | A1     | 0         | 0.02 | 0.05 |  |
| MOLD THICKNESS         |           | A2     |           | 0.55 |      |  |
| L/F THICKNESS          |           | A3     | 0.203 REF |      |      |  |
| LEAD WIDTH             |           | ь      | 0.2       | 0.25 | 0.3  |  |
| BODY SIZE              | ×         | D      | 2 BSC     |      |      |  |
| BODT SIZE              | Y         | E      | 2 BSC     |      |      |  |
| LEAD PITCH             | EAD PITCH |        | e 0.5 BSC |      |      |  |
| EP SIZE                | ×         | D2     | 0.7       | 0.8  | 0.9  |  |
| EF SIZE                | Y         | E2     | 1.4       | 1.5  | 1.6  |  |
| LEAD LENGTH            |           | L      | 0.2       | 0.3  | 0.4  |  |
| LEAD TIP TO EXPOSED I  | PAD EDGE  | к      | 0.3 REF   |      |      |  |
| PACKAGE EDGE TOLERANCE |           | aaa    | 0.1       |      |      |  |
| MOLD FLATNESS          |           | ccc    | 0.1       |      |      |  |
| COPLANARITY            |           | eee    | 0.05      |      |      |  |
|                        |           | bbb    | 0.1       |      |      |  |
| LEAD OFFSET            |           | ddd    | 0.05      |      |      |  |
| EXPOSED PAD OFFSET     |           | fff    | 0.1       |      |      |  |
|                        |           |        |           |      |      |  |
|                        |           |        |           |      |      |  |
|                        |           |        |           |      |      |  |

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## **Recommended Land Patter**

Unit: mm



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